74HC123-Q100; 74HCT123-Q100

Dual retriggerable monostable multivibrator with reset

Rev. 2 — 19 January 2015

Product data sheet

1. General description

The 74HC123-Q100; 74HCT123-Q100 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC123-Q100; 74HCT123-Q100 are dual retriggerable monostable multivibrators with output pulse width control by three methods:

- The basic pulse is defined by the selection of the external resistor (R_{EXT}) and capacitor (C_{EXT}).
- 2. Once triggered, the basic output pulse width may be extended by retriggering the gated active LOW-going edge input (nA) or the active HIGH-going edge input (nB). By repeating this process, the output pulse period (nQ = HIGH, nQ = LOW) can be made as long as desired. Alternatively an output delay can be terminated at any time by a LOW-going edge on input nRD, which also inhibits the triggering.
- 3. An internal connection from nRD to the input gates makes it possible to trigger the circuit by a HIGH-going signal at input nRD as shown in Table 3.

Schmitt trigger action in the $n\overline{A}$ and nB inputs, makes the circuit highly tolerant to slower input rise and fall times.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- Direct reset terminates output pulse
- Schmitt trigger action on all inputs except for the reset input
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ♦ MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

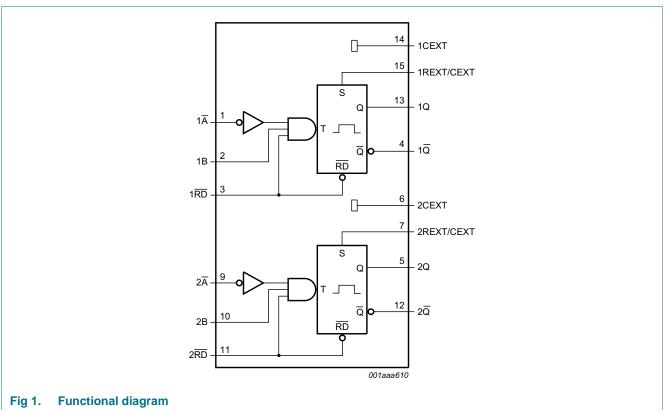


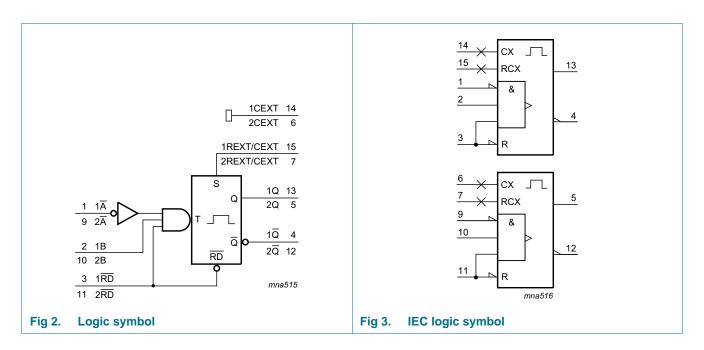
3. Ordering information

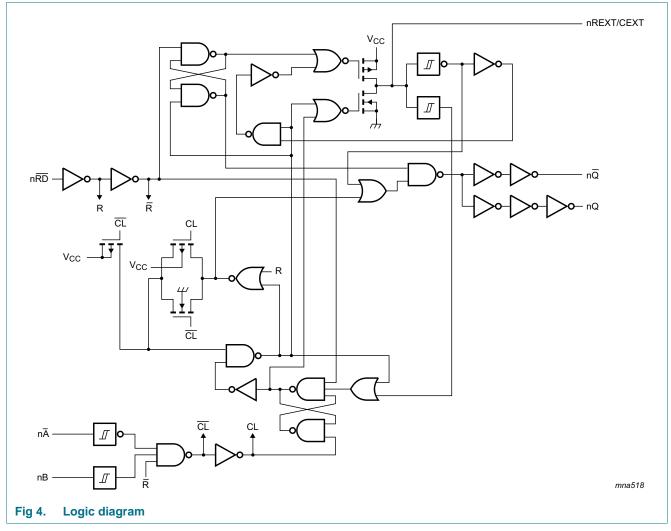
Table 1. Ordering information

Type number	Package							
	Temperature range Name Description							
74HC123D-Q100	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1				
74HCT123D-Q100			body width 3.9 mm					
74HC123PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1				
74HCT123PW-Q100			body width 4.4 mm					
74HC123BQ-Q100	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	SOT763-1				

4. Functional diagram

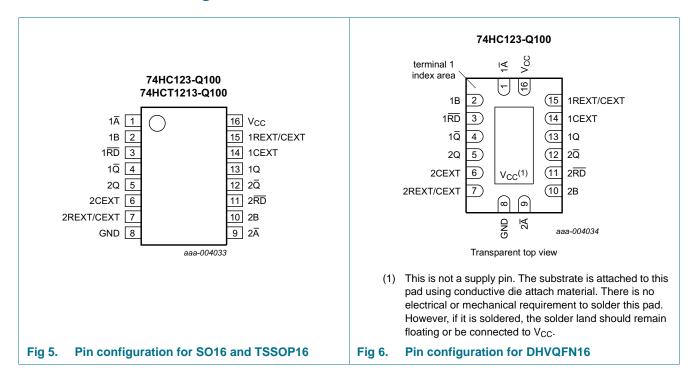






5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description	
1Ā	1	negative-edge triggered input 1	
1B	2	positive-edge triggered input 1	
1RD	3	direct reset LOW and positive-edge triggered input 1	
1Q	4	active LOW output 1	
2Q	5	active HIGH output 2	
2CEXT	6	external capacitor connection 2	
2REXT/CEXT	7	external resistor and capacitor connection 2	
GND	8	ground (0 V)	
2Ā	9	negative-edge triggered input 2	
2B	10	positive-edge triggered input 2	
2RD	11	direct reset LOW and positive-edge triggered input 2	
2Q	12	active LOW output 2	
1Q	13	active HIGH output 1	
1CEXT	14	external capacitor connection 1	
1REXT/CEXT	15	external resistor and capacitor connection 1	
V _{CC}	16	supply voltage	

6. Functional description

Table 3. Function table[1]

Input nRD			Output	
nRD	nĀ	nB	nQ	nQ
L	X	X	L	Н
X	Н	Х	<u>[2]</u>	H[2]
Χ	X	L	<u>[2]</u>	H[2]
Н	L	\uparrow	Л	Т
Н	\	Н	Л	T
\uparrow	L	Н	Л	T

- [1] H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = LOW-to-HIGH transition; ↓ = HIGH-to-LOW transition;
 - = one HIGH level output pulse; = one LOW level output pulse.
- [2] If the monostable was triggered before this condition was established, the pulse continues as programmed.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$		-	±20	mA
Io	output current	except for pins nREXT/CEXT; $V_O = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$		-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-	-50	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation					
	SO16 package		[1]	-	500	mW
	TSSOP16 package		[2]	-	500	mW
	DHVQFN16 package		[3]	-	500	mW

- [1] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 °C.
- [2] For TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.
- [3] For DHVQFN16 packages: P_{tot} derates linearly with 4.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	74H	IC123-Q	100	74H	CT123-0	Q100	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
Δt/ΔV	input transition rise and	nRD input							
	fall rate	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
		V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	–40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC123	-Q100									
V _{IH}	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V_{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A$; $V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL}								
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μА
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μА

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT12	23-Q100				'			1	'	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	8.0	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
V_{OL}	LOW-level	$V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = 20 μA	-	0	0.1	-	0.1	-	0.1	V
		I _O = 4.0 mA	-	0.15	0.26	-	0.33	-	0.4	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	-	80	-	160	μА
Δl _{CC}	additional supply current	per input pin; $I_O = 0$ A; $V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $V_{CC} = 4.5$ V to 5.5 V								
		pins nĀ, nB	-	35	125	-	160	-	170	μΑ
		pin nRD	-	50	180	-	225	-	245	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \ pF$ unless otherwise specified; for test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC12	3-Q100						-	1		
t _{pd}	propagation delay	nRD, nA, nB to nQ or nQ; $C_{EXT} = 0$ pF; $R_{EXT} = 5$ k Ω ; see Figure 9	1							
		V _{CC} = 2.0 V	-	83	255	-	320	-	385	ns
		V _{CC} = 4.5 V	-	30	51	-	64	-	77	ns
		V _{CC} = 5 V; C _L = 15 pF	-	26	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	24	43	-	54	-	65	ns
		$\overline{\text{NRD}}$ (reset) to $\overline{\text{NQ}}$ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9								
		V _{CC} = 2.0 V	-	66	215	-	270	-	325	ns
		V _{CC} = 4.5 V	-	24	43	-	54	-	65	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$	-	20	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	19	37	-	46	-	55	ns
t _t	transition	see Figure 9	1							
•	time	V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns
t_{W}	pulse width	nA LOW; see Figure 10								
		V _{CC} = 2.0 V	100	8	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	3	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	2	-	21	-	26	-	ns
		nB HIGH; see Figure 10								
		V _{CC} = 2.0 V	100	17	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	6	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	5	-	21	-	26	-	ns
		nRD LOW; see Figure 11								
		V _{CC} = 2.0 V	100	14	-	125	-	150	-	ns
		V _{CC} = 4.5 V	20	5	-	25	-	30	-	ns
		V _{CC} = 6.0 V	17	4	-	21	-	26	-	ns
		nQ HIGH and n \overline{Q} LOW; $V_{CC} = 5.0 \text{ V}$; see Figure 10 and Figure 11	1							
		$C_{EXT} = 100 \text{ nF}; R_{EXT} = 10$ k Ω	-	450	-	-	-	-	-	μS
		$C_{EXT} = 0 pF; R_{EXT} = 5 k\Omega$	-	75	-	-	-	-	-	ns

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions			25 °C		–40 °C to	o +85 °C	–40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
t _{rtrig}	retrigger time	\overline{NA} , nB; $C_{EXT} = 0$ pF; $R_{EXT} = 0$ 5 k Ω ; $V_{CC} = 5.0$ V; see Figure 10	[3][4]	-	110	-	-	-	-	-	ns
R_{EXT}	external	see Figure 7									
	resistance	V _{CC} = 2.0 V		10	-	1000	-	-	-	-	kΩ
		$V_{CC} = 5.0 \text{ V}$		2	-	1000	-	-	-	-	$k\Omega$
C _{EXT}	external capacitance	tance		-	-	-	-	-	-	-	pF
C _{PD}	power dissipation capacitance	per monostable; $V_I = GND$ [5] to V_{CC}		-	54	-	-	-	-	-	pF
74HCT12	23-Q100							I .	1		
t _{PHL}	HIGH to LOW propagation	$\overline{\text{NRD}}$, $\overline{\text{NA}}$, $\overline{\text{NB}}$ to $\overline{\text{NQ}}$ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9									
	delay	V _{CC} = 4.5 V		-	30	51	-	64	-	77	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	26	-	-	-	-	-	ns
		$\overline{\text{NRD}}$ (reset) to nQ or n $\overline{\text{Q}}$; $C_{\text{EXT}} = 0$ pF; $R_{\text{EXT}} = 5$ k Ω ; see Figure 9									
		V _{CC} = 4.5 V		-	27	46	-	58	-	69	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	23	-	-	-	-	-	ns
t _{PLH}	LOW to HIGH propagation	\overline{NRD} , NR									
	delay	V _{CC} = 4.5 V		-	28	51	-	64	-	77	ns
		$V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$		-	26	-	-	-	-	-	ns
		$\overline{\text{NRD}}$ (reset) to nQ or $\overline{\text{NQ}}$; $C_{\text{EXT}} = 0 \text{ pF}$; $R_{\text{EXT}} = 5 \text{ k}\Omega$; see Figure 9									
		V _{CC} = 4.5 V		-	23	46	-	58	-	69	ns
		V _{CC} = 5 V; C _L = 15 pF		-	23	-	-	-	-	-	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 9</u>	<u>[1]</u>	-	7	15	-	19	-	22	ns
t _W	pulse width	V _{CC} = 4.5 V									
		nA LOW; see Figure 10		20	3	-	25	-	30	-	ns
		nB HIGH; see Figure 10		20	5	-	25	-	30	-	ns
		nRD LOW; see Figure 11		20	7	-	25	-	30	-	ns
		nQ HIGH and n \overline{Q} LOW; V_{CC} = 5.0 V; see <u>Figure 10</u> and <u>Figure 11</u>	[2]								
		$C_{EXT} = 100 \text{ nF}; R_{EXT} = 10 \text{ k}\Omega$		-	450	-	-	-	-	-	μS
		$C_{EXT} = 0 \text{ pF}; R_{EXT} = 5 \text{ k}\Omega$		-	75	-	-	-	-	-	ns

74HC_HCT123_Q100

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit see Figure 12.

	_	a								
Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _{rtrig}	retrigger time	$n\overline{A}$, nB; $C_{EXT} = 0$ pF; $R_{EXT} = 3$ 4 5 k Ω ; $V_{CC} = 5.0$ V; see Figure 10	-	110	-	-	-	-	-	ns
R _{EXT}	external timing resistor	V _{CC} = 5.0 V; see <u>Figure 7</u>	2	-	1000	-	-	-	-	kΩ
C _{EXT}	external timing capacitor	V _{CC} = 5.0 V; see <u>Figure 7</u> [4]	-	-	-	-	-	-	-	pF
C _{PD}	power dissipation capacitance	per monostable; [5] $V_I = GND$ to $V_{CC} - 1.5 \text{ V}$	-	56	-	-	-	-	-	pF

- [1] t_{pd} is the same as t_{PHL} and t_{PLH} ; t_t is the same as t_{THL} and t_{TLH}
- [2] For other R_{EXT} and C_{EXT} combinations, see Figure 7. If C_{EXT} > 10 nF, the following formula is valid.

 $t_W = K \times R_{EXT} \times C_{EXT}$, where:

t_W = typical output pulse width in ns;

 R_{EXT} = external resistor in $k\Omega$;

C_{EXT} = external capacitor in pF;

K = constant = 0.45 for $V_{CC} = 5.0$ V and 0.55 for $V_{CC} = 2.0$ V.

The inherent test jig and pin capacitance at pins 15 and 7 (nREXT/CEXT) is approximately 7 pF.

[3] The time to retrigger the monostable multivibrator depends on the values of R_{EXT} and C_{EXT} . The output pulse width is only extended when the time between the active-going edges of the trigger input pulses meets the minimum retrigger time. If $C_{\text{EXT}} > 10$ pF, the next formula (at $V_{\text{CC}} = 5.0$ V) for the setup time of a retrigger pulse is valid:

$$t_{rtrig}$$
 = 30 + 0.19 × R_{EXT} × $C_{EXT}^{0.9}$ + 13 × $R_{EXT}^{1.05}$, where:

 t_{rtrig} = retrigger time in ns;

 C_{EXT} = external capacitor in pF; R_{EXT} = external resistor in k Ω .

The inherent test jig and pin capacitance at pins 15 and 7 (nREXT/CEXT) is 7 pF.

- [4] When the device is powered-up, initiate the device via a reset pulse, when $C_{EXT} < 50$ pF.
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum (C_L \times V_{CC}{}^2 \times f_o) + 0.75 \times C_{EXT} \times V_{CC}{}^2 \times f_o + D \times 16 \times V_{CC} \text{ where:}$$

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

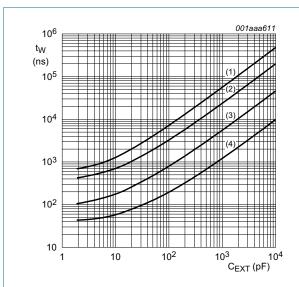
D = duty factor in %;

 C_1 = output load capacitance in pF;

V_{CC} = supply voltage in V;

C_{EXT} = timing capacitance in pF;

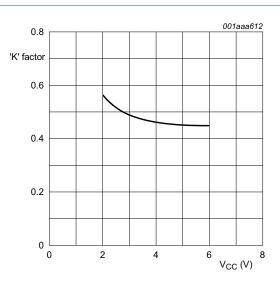
 $\sum (C_L \times V_{CC}{}^2 \times f_o)$ sum of outputs.



 V_{CC} = 5.0 V; T_{amb} = 25 °C.

- (1) $R_{EXT} = 100 \text{ k}\Omega$
- (2) $R_{EXT} = 50 \text{ k}\Omega$
- (3) $R_{EXT} = 10 \text{ k}\Omega$
- (4) $R_{EXT} = 2 k\Omega$

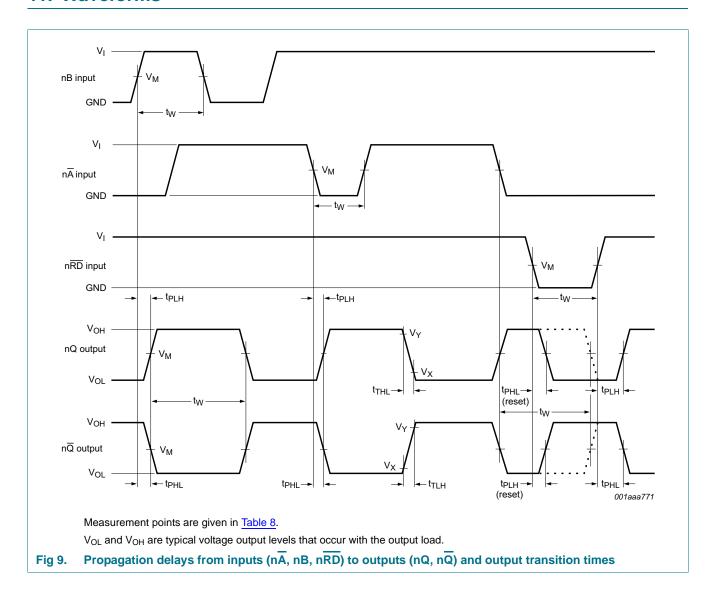
Fig 7. Typical output pulse width as a function of the external capacitor value

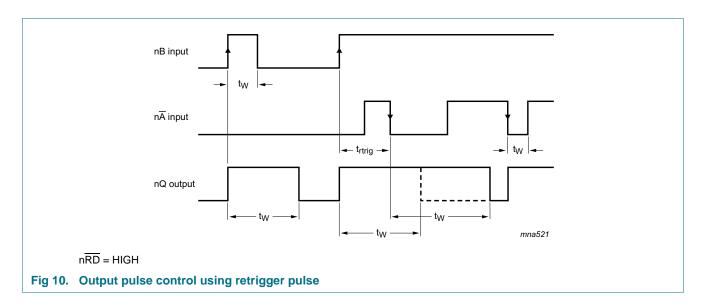


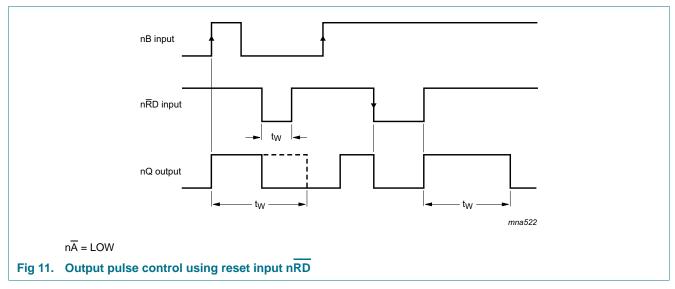
 C_{EXT} = 10 nF; R_{EXT} = 10 k Ω to 100 k Ω . T_{amb} = 25 °C.

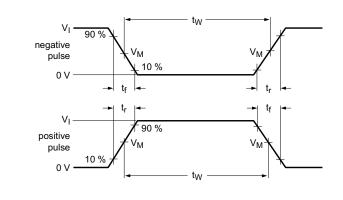
Fig 8. 74HC123-Q100 typical 'K' factor as function of V_{CC}

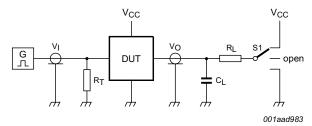
11. Waveforms











Test data is given in Table 8.

Definitions test circuit:

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

 R_L = Load resistance.

S1 = Test selection switch.

Fig 12. Test circuit for measuring switching times

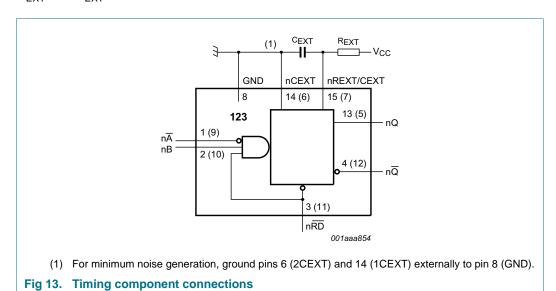
Table 8. Test data

Туре	Input		Load	S1 position	
	VI	t _r , t _f	CL	R _L	t _{PHL} , t _{PLH}
74HC123-Q100	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open
74HCT123-Q100	3 V	6 ns	15 pF, 50 pF	1 kΩ	open

12. Application information

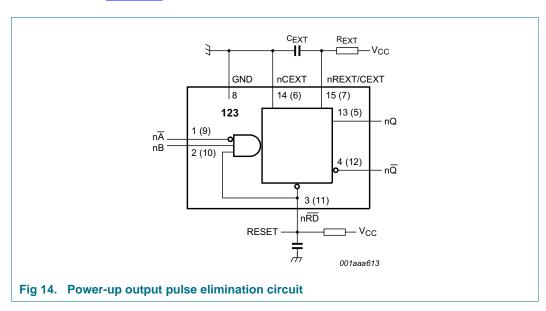
12.1 Timing component connections

The basic output pulse width is defined by the values of the external timing components R_{EXT} and C_{EXT} .



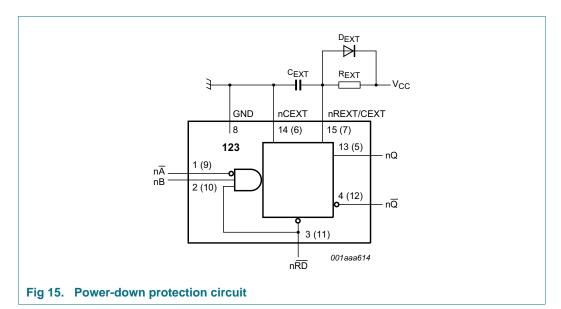
12.2 Power-up considerations

When the monostable is powered-up, it may produce an output pulse, with a pulse width defined by the values of R_{EXT} and C_{EXT} . This output pulse can be eliminated using the circuit shown in Figure 14.



12.3 Power-down considerations

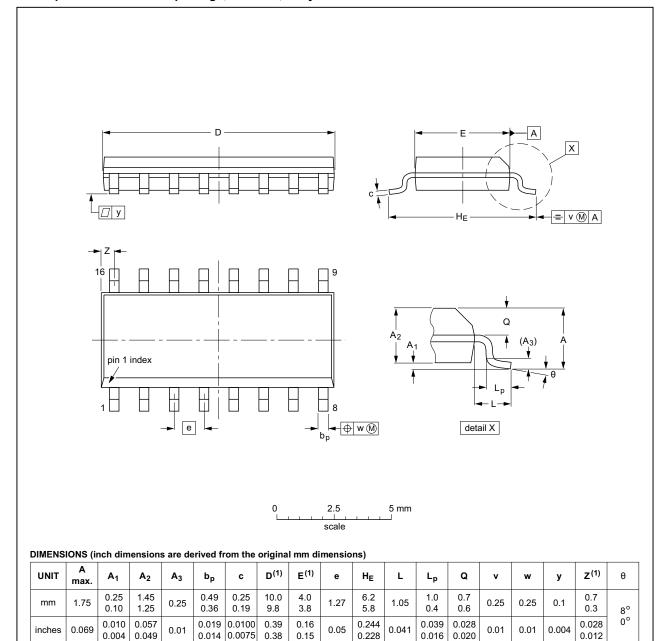
A large capacitor C_{EXT} may cause problems when powering-down the monostable due to the energy stored in this capacitor. When a system containing this device is powered-down or a rapid decrease of V_{CC} to zero occurs, the monostable may sustain damage. The damage is due to the capacitor discharging through the input protection diodes. To avoid this possibility, use a damping diode (D_{EXT}) and connect as shown in Figure 15. D_{EXT} is preferably a germanium or Schottky type diode able to withstand large current surges.



13. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				99-12-27 03-02-19

Fig 16. Package outline SOT109-1 (SO16)

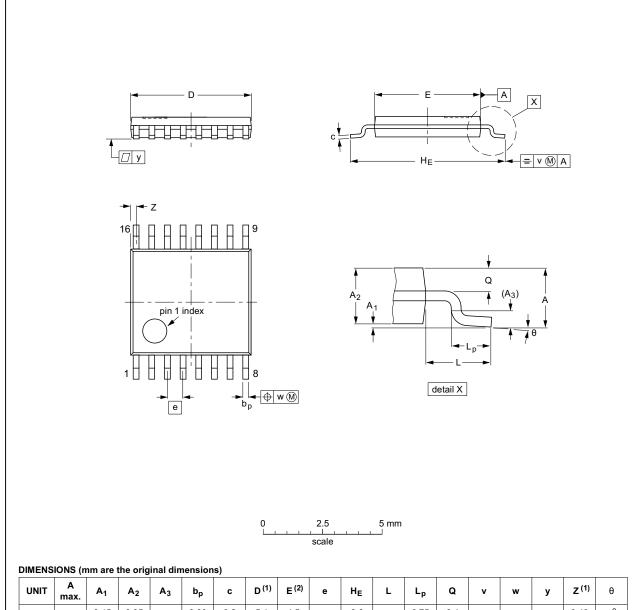
74HC_HCT123_Q100

All information provided in this document is subject to legal disclaimers.

© NXP Semiconductors N.V. 2015. All rights reserved.

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D (1)	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

				ISSUE DATE	
IEC	JEDEC	JEITA	PROJECTION		
	MO-153			99-12-27 03-02-18	

Fig 17. Package outline SOT403-1 (TSSOP16)

74HC_HCT123_Q100

All information provided in this document is subject to legal disclaimers.

© NXP Semiconductors N.V. 2015. All rights reserved.

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

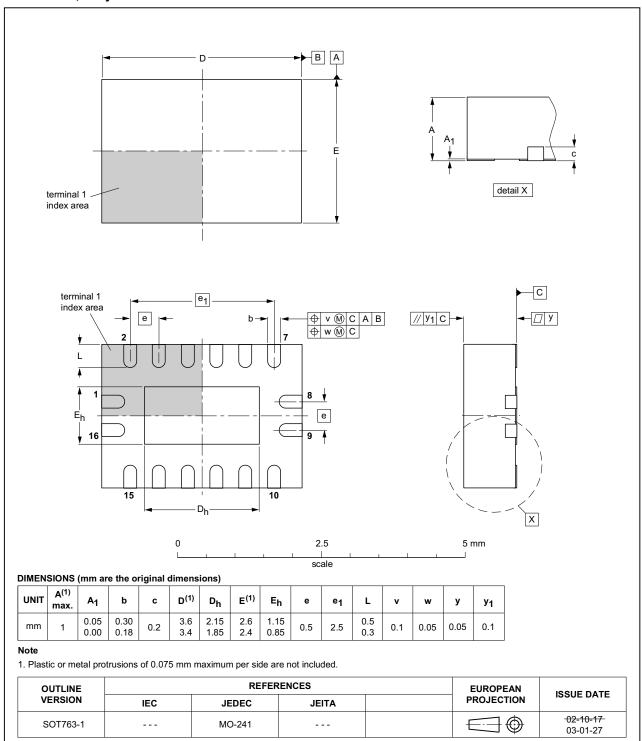


Fig 18. Package outline SOT763-1 (DHVQFN16)

74HC_HCT123_Q100

All information provided in this document is subject to legal disclaimers.

© NXP Semiconductors N.V. 2015. All rights reserved.

14. Abbreviations

Table 9. Abbreviations

Acronym	Abbreviation		
CMOS Complementary Metal Oxide Semiconductor			
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
HBM	Human Body Model		
LSTTL	Low-power Schottky Transistor-Transistor Logic		
MM	Machine Model		
MIL	Military		

15. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74HC_HCT123_Q100 v.2	20150119	Product data sheet	-	74HC_HCT123_Q100 v.1		
Modifications:	<u>Table 7</u> : Power dissipation capacitance condition for 74HCT123-Q100 is corrected.					
74HC_HCT123_Q100 v.1	20120801	Product data sheet	-	-		

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition					
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.					
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.					
Product [short] data sheet	Production	This document contains the product specification.					

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

74HC_HCT123_Q100

74HC123-Q100; 74HCT123-Q100

Dual retriggerable monostable multivibrator with reset

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

74HC123-Q100; 74HCT123-Q100

NXP Semiconductors

Dual retriggerable monostable multivibrator with reset

18. Contents

1	General description
2	Features and benefits
3	Ordering information 2
4	Functional diagram 2
5	Pinning information 4
5.1	Pinning 4
5.2	Pin description 4
6	Functional description 5
7	Limiting values 5
8	Recommended operating conditions 6
9	Static characteristics 6
10	Dynamic characteristics 8
11	Waveforms
12	Application information
12.1	Timing component connections
12.2	Power-up considerations
12.3	Power-down considerations 16
13	Package outline
14	Abbreviations
15	Revision history
16	Legal information
16.1	Data sheet status 21
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks22
17	Contact information 22
18	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.